



DMG1012UWQ

### **Product Summary**

BV <sub>DSS</sub>	R <sub>DS(ON)</sub> Max	I <sub>D</sub> Max T <sub>A</sub> = +25°C
	0.45Ω @ V <sub>GS</sub> = 4.5V	0.95A
20V	0.6Ω @ V <sub>GS</sub> = 2.5V	0.82A
	0.75Ω @ VGS = 1.8V	0.73A

# **Description and Applications**

This MOSFET has been designed to minimize the on-state resistance (R<sub>DS(ON)</sub>) yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- General Purpose Interfacing Switch
- Power Management Functions
- DC-DC Converters
- Analog Switch

## Features and Benefits

- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- ESD Protected
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)

N-CHANNEL ENHANCEMENT MODE MOSFET

- Halogen and Antimony Free. "Green" Device (Note 3)
- The DMG1012UWQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/guality/product-definitions/

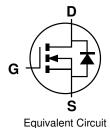
## **Mechanical Data**

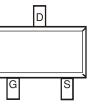
- Case: SOT323
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.027 grams (Approximate)





Top View





Top View

## Ordering Information (Note 4)

Part Number	Case	Packaging
DMG1012UWQ-7	SOT323	3000 / Tape & Reel
DMG1012UWQ-13	SOT323	10000 / Tape & Reel

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

## **Marking Information**

Π	
BE2	ΨM

 $\begin{array}{l} \mathsf{BE2} = \mathsf{Product} \ \mathsf{Type} \ \mathsf{Marking} \ \mathsf{Code} \\ \overline{\mathsf{Y}}\mathsf{M} = \mathsf{Date} \ \mathsf{Code} \ \mathsf{Marking} \\ \overline{\mathsf{Y}} = \mathsf{Year} \ (\mathsf{ex:} \ \mathsf{H} = 2020) \end{array}$ 

M = Month (ex: 9 = September)

2020	2021	2022	2023	2024	2025	2026	2027	2028	2029	2030	
Н		J	K	L	М	Ν	0	Р	R	S	
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Jan	Feb	Mar	Apr	мау	Jun	Jui	Aug	Sep	UCI	NOV	
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2031 T Dec



# Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristi	Symbol	Value	Unit		
Drain-Source Voltage	VDSS	20	V		
Gate-Source Voltage	V <sub>GSS</sub>	±6	V		
Continuous Drain Current (Note 6) $V_{GS}$ = 4.5V	Steady State	TA = +25°C TA = +85°C	١D	0.95 0.75	А
Pulsed Drain Current (10µs Pulse, Duty Cycle=1%)	Ідм	6	Α		
Maximum Body Diode Forward Current (Note 5)	ls	0.58	A		

## **Thermal Characteristics**

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)		PD	0.46	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	R <sub>θJA</sub>	269	°C/W
Total Power Dissipation (Note 6)		PD	0.61	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	RθJA	205	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

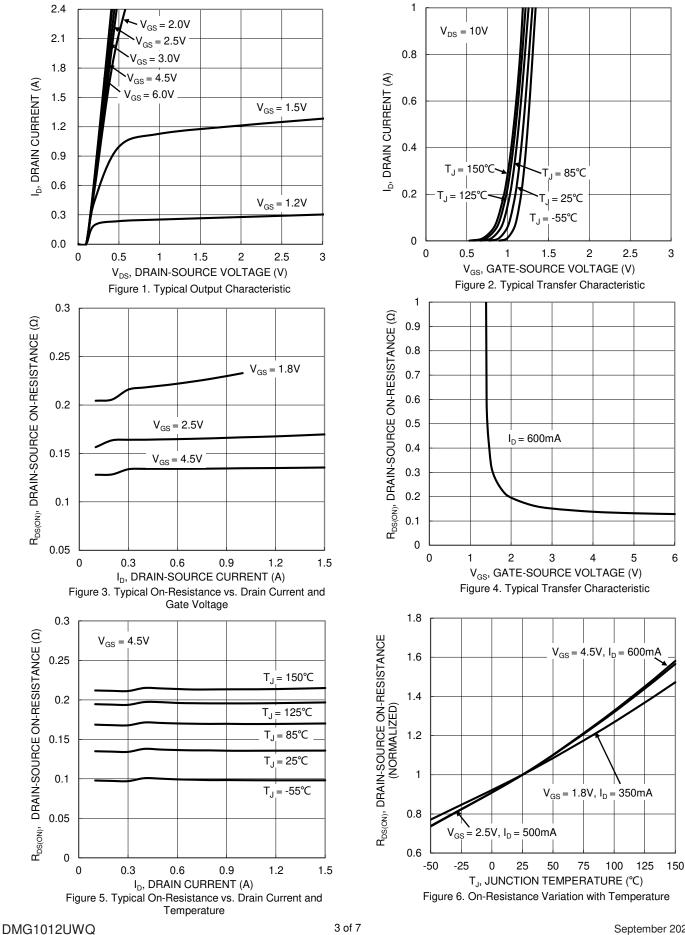
Characteristic	Symbol	Min	Тур	Мах	Unit	Test Condition			
OFF CHARACTERISTICS (Note 7)	Symbol	IVIIII	ιyp	IVIAA	Onit	Test condition			
Drain-Source Breakdown Voltage	BVDSS	20		_	V	V <sub>GS</sub> = 0V, I <sub>D</sub> = 250µA			
Zero Gate Voltage Drain Current $T_J = +25^{\circ}C$	IDSS	_		100	nA	$V_{DS} = 20V, V_{GS} = 0V$			
Gate-Source Leakage	lgss	_		±1.0	μA	$V_{GS} = \pm 4.5V, V_{DS} = 0V$			
ON CHARACTERISTICS (Note 7)									
Gate Threshold Voltage	VGS(TH)	0.5		1.0	V	$V_{DS} = V_{GS}$ , $I_D = 250 \mu A$			
			0.13	0.45		V <sub>GS</sub> = 4.5V, I <sub>D</sub> = 600mA			
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>	—	0.16	0.6	Ω	$V_{GS} = 2.5V, I_D = 500mA$			
			0.21	0.75		V <sub>GS</sub> = 1.8V, I <sub>D</sub> = 350mA			
Diode Forward Voltage	Vsd	_	0.7	1.2	V	V <sub>GS</sub> = 0V, I <sub>S</sub> = 150mA			
DYNAMIC CHARACTERISTICS (Note 8)	•								
Input Capacitance	Ciss	—	43	—	pF				
Output Capacitance	Coss	—	12	—	pF	Vps = 16V, Vgs = 0V, f = 1.0MHz			
Reverse Transfer Capacitance	Crss	_	7	_	pF	1 = 1.00012			
Total Gate Charge	Qg		1.0	_	nC				
Gate-Source Charge	Qgs	—	0.2	—	nC	$V_{GS} = 4.5V, V_{DS} = 10V,$			
Gate-Drain Charge	Qgd	—	0.1		nC	I <sub>D</sub> = 250mA			
Turn-On Delay Time	t <sub>D(ON)</sub>	—	5.2	—	ns				
Turn-On Rise Time	tR	—	2.1	—	ns	$V_{DD} = 10V, V_{GS} = 4.5V,$			
Turn-Off Delay Time	t <sub>D(OFF)</sub>	—	452	—	ns	R <sub>L</sub> = 47Ω, R <sub>G</sub> = 10Ω, I <sub>D</sub> = 200mA			
Turn-Off Fall Time	tF	—	239		ns				

5. Device mounted on FR-4 substrate PC board, with minimum recommended pad layout. Notes:

Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.
Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to production testing.



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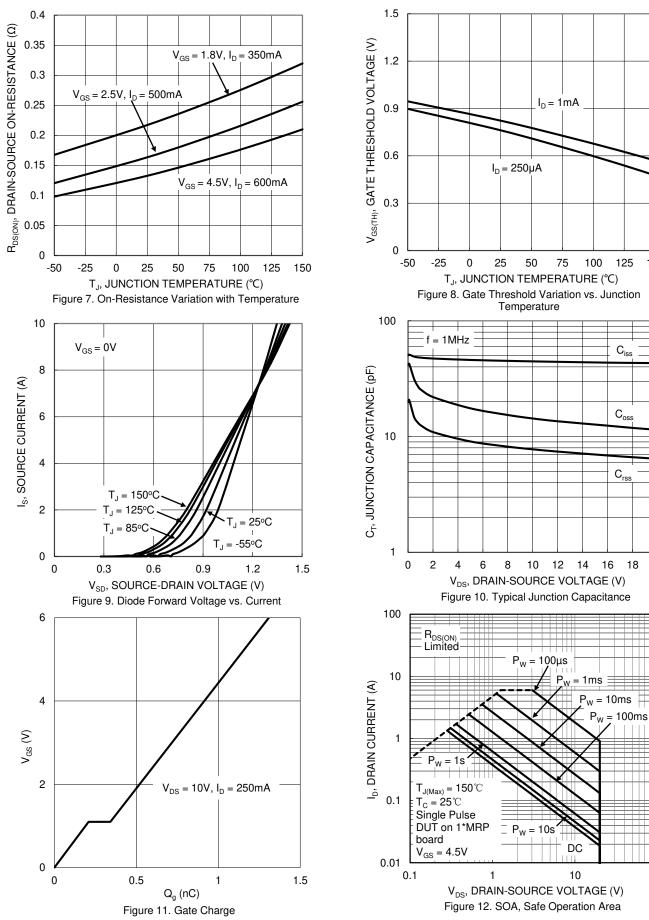
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## DMG1012UWQ

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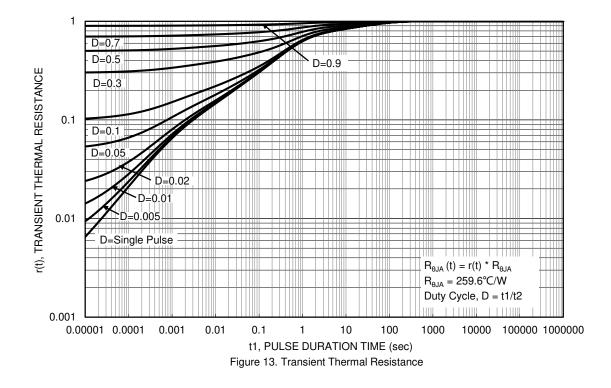
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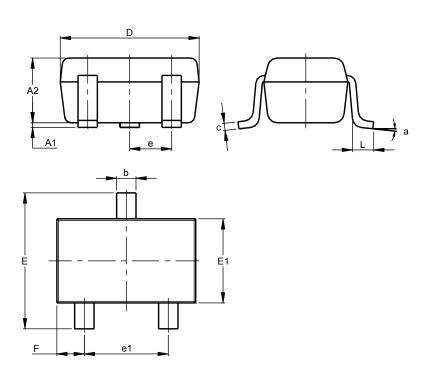






## **Package Outline Dimensions**

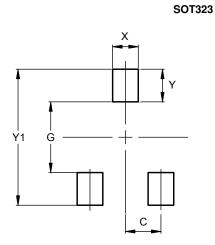
Please see http://www.diodes.com/package-outlines.html for the latest version.



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SOT323								
Dim	Min	Max	Тур					
A1	0.00	0.10	0.05					
A2	0.90	1.00	0.95					
b	0.25	0.40	0.30					
С	0.10	0.18	0.11					
D	1.80	2.20	2.15					
Е	2.00	2.20	2.10					
E1	1.15	1.35	1.30					
е	C	).650 B	SC					
e1	1.20	1.40	1.30					
F	0.375	0.475	0.425					
L	0.25	0.40	0.30					
а	0°	8°						
All	All Dimensions in mm							

## **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
С	0.650
G	1.300
Х	0.470
Y	0.600
Y1	2.500

### SOT323



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